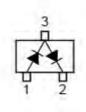


## **BAV99** SWITCHING DIODES FEATURES

Fast Switching Speed For General Purpose Switching Applications High Conductance





Marking Code: A7 SOT-23 Plastic Package

### Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	85	V
Continuous Reverse Voltage	V <sub>R</sub>	75	V
Continuous Forward Current (Double Diode Loaded)	١ <sub>F</sub>	125	mA
Continuous Forward Current (Single Diode Loaded)	١ <sub>F</sub>	215	mA
Repetitive Peak Forward Current	I <sub>FRM</sub>	450	mA
Non-repetitive Peak Forward Surge Current at t = 1 s at t = 1 ms at t = 1 µs	I <sub>FSM</sub>	0.5 1 4.5	А
Power Dissipation	P <sub>tot</sub>	350	mW
Junction Temperature	Tj	150	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C

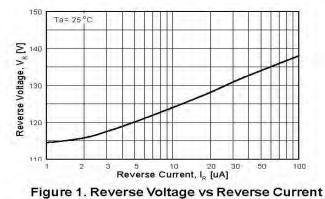
### Characteristics at T<sub>a</sub> = 25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 50 \text{ mA}$ at $I_F = 150 \text{ mA}$	V <sub>F</sub>	0.715 0.855 1 1.25	V
Reverse Current at $V_R = 25 V$ at $V_R = 75 V$ at $V_R = 25 V$ , $T_j = 150 °C$ at $V_R = 75 V$ , $T_j = 150 °C$	I <sub>R</sub>	30 1 30 50	nA μA μA μA
Diode Capacitance at $V_R = 0$ , f = 1 MHz	C <sub>d</sub>	1.5	pF
Reverse Recovery Time at $I_F = I_R = 10$ mA, $I_R = 1$ mA, $R_L = 100$ $\Omega$	t <sub>rr</sub>	4	ns





# **Typical Characteristics**



BV - 1.0 to 100uA

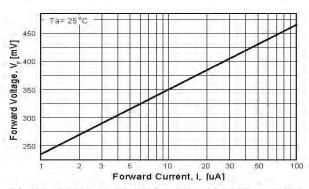


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

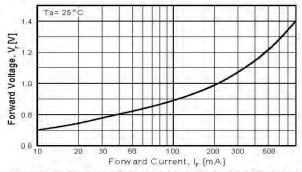
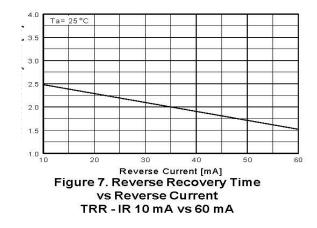
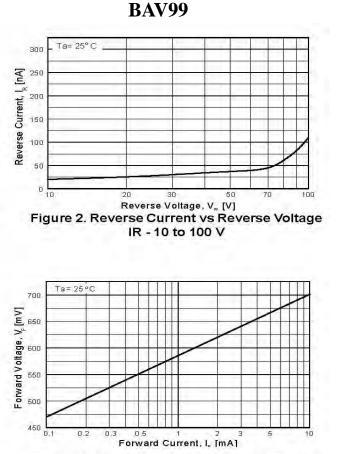
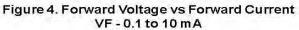


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA







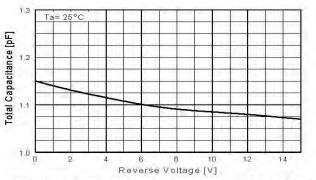
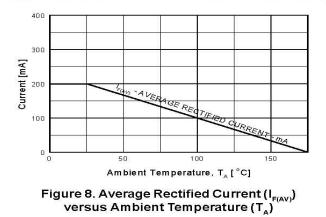


Figure 6. Total Capacitance vs Reverse Voltage





### PACKAGE OUTLINE

**SOT-23** 

### Plastic surface mounted package; 3 leads

